

PC817X Series

*4-channel package type is also available. (model No. **PC847X Series**)

DIP 4pin General Purpose Photocoupler



■ Description

PC817X Series contains an IRED optically coupled to a phototransistor.

It is packaged in a 4pin DIP, available in wide-lead spacing option and SMT gullwing lead-form option.

Input-output isolation voltage(rms) is 5.0kV.

Collector-emitter voltage is 80V^(*) and CTR is 50% to 600% at input current of 5mA.

■ Features

- 1. 4pin DIP package
- 2. Double transfer mold package (Ideal for Flow Soldering)
- 3. High collector-emitter voltage (V_{CEO}:80V(*))
- 4. Current transfer ratio (CTR : MIN. 50% at $I_F=5$ mA, $V_{CF}=5V$)
- 5. Several CTR ranks available
- 6. High isolation voltage between input and output (V_{iso(rms)}: 5.0 kV)
 - (*) Up to Date code "P7" (July 2002) V_{CEO} : 35V. From the production Date code "J5" (May 1997) to "P7" (July 2002), however the products were screened by BV_{CEO}≥70V.

■ Agency approvals/Compliance

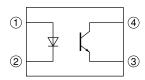
- Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. PC817)
- 2. Package resin : UL flammability grade (94V-0)

■ Applications

- 1. I/O isolation for MCUs (Micro Controller Units)
- 2. Noise suppression in switching circuits
- Signal transmission between circuits of different potentials and impedances



■ Internal Connection Diagram

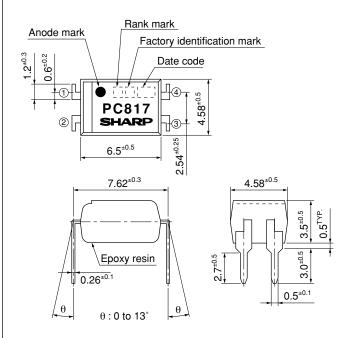


- ① Anode
- ② Cathode
- 3 Emitter
- 4 Collector

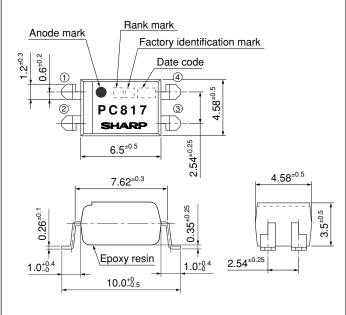
■ Outline Dimensions

(Unit:mm)

1. Through-Hole [ex. PC817X]



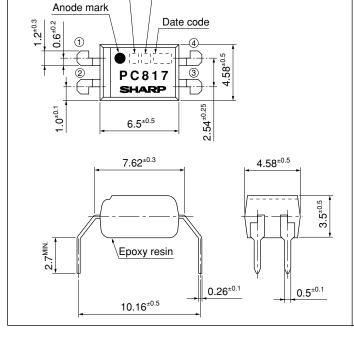
2. SMT Gullwing Lead-Form [ex. PC817XI]



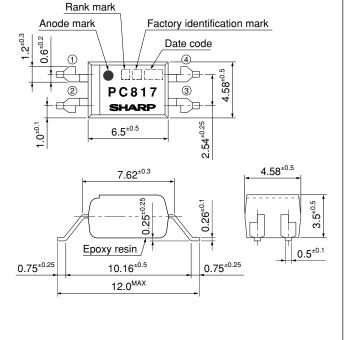
3. Wide Through-Hole Lead-Form [ex. PC817XF]

Factory identification mark

Rank mark



4. Wide SMT Gullwing Lead-Form [ex. PC817XFP]



Product mass: approx. 0.21g



Date code (2 digit)

	1st o	digit		2nd digit		
	Year of p	roduction		Month of production		
A.D.	Mark	A.D	Mark	Month	Mark	
1990	A	2002	P	January	1	
1991	В	2003	R	February	2	
1992	С	2004	S	March	3	
1993	D	2005	T	April	4	
1994	Е	2006	U	May	5	
1995	F	2007	V	June	6	
1996	Н	2008	W	July	7	
1997	J	2009	X	August	8	
1998	K	2010	A	September	9	
1999	L	2011	В	October	0	
2000	M	2012	С	November	N	
2001	N	:	:	December	D	

repeats in a 20 year cycle

Factory identification mark

Factory identification Mark	Country of origin		
no mark	Tomon		
	- Japan		
	Indonesia		
$\overline{\hspace{1cm}}$	Philippines		
_	China		

^{*} This factory marking is for identification purpose only.

Please contact the local SHARP sales representative to see the actural status of the production.

Rank mark

Refer to the Model Line-up table



■ Absolute Maximum Ratings

	■ Absolute Maximum Ratings (T _a =25°C							
	Parameter	Symbol	Rating	Unit				
	Forward current	I_{F}	50	mA				
Input	*1 Peak forward current	I_{FM}	1	A				
Inj	Reverse voltage	V_R	6	V				
	Power dissipation	P	70	mW				
	Collector-emitter voltage	V_{CEO}	*4 80	V				
Output	Emitter-collector voltage	V_{ECO}	6	V				
Out	Collector current	I_C	50	mA				
	Collector power dissipation	P_{C}	150	mW				
	Γotal power dissipation	P_{tot}	200	mW				
*2 Isolation voltage		V _{iso (rms)}	5.0	kV				
Operating temperature		T_{opr}	-30 to +100	°C				
Storage temperature		T _{stg}	-55 to +125	°C				
*3 €	Soldering temperature	T_{sol}	260	°C				

■ Electro-optical Characteristics

 $(T_a=25^{\circ}C)$

- (-a					(u /			
Parameter			Symbol	Conditions	MIN.	TYP.	MAX.	Unit
	Forward voltage		V_F	$I_F=20mA$	_	1.2	1.4	V
Input	Peak forward voltage		V_{FM}	$I_{FM}=0.5A$	_	-	3.0	V
InI	Reverse current		I_R	$V_R=4V$	_	-	10	μΑ
	Terminal capacitas	nce	C_{t}	V=0, $f=1kHz$	_	30	250	pF
ut	Collector dark cur	rent	I_{CEO}	$V_{CE}=50V, I_{F}=0$	_	_	100	nA
Output	Collector-emitter breakdown voltage		BV _{CEO}	I_{C} =0.1mA, I_{F} =0	*5 80	_	_	V
Ō	Emitter-collector breakdown voltage		BV _{ECO}	$I_{E}=10\mu A, I_{F}=0$	6	-	-	V
SS	Collector current		I_{C}	$I_F=5mA, V_{CE}=5V$	2.5	-	30.0	mA
risti	Collector-emitter saturat	ion voltage	V _{CE (sat)}	$I_F=20\text{mA}, I_C=1\text{mA}$	_	0.1	0.2	V
acte	Isolation resistance	e	R _{ISO}	DC500V, 40 to 60%RH	5×10 ¹⁰	1×10 ¹¹	_	Ω
fer characteristics	Floating capacitance		$C_{\rm f}$	V=0, f=1MHz	-	0.6	1.0	pF
	Cut-off frequency		f_c	V_{CE} =5V, I_{C} =2mA, R_{L} =100 Ω , -3dB	_	80	_	kHz
Transfer	Dagnanga tima	Rise time	$t_{\rm r}$	V 2V I 2m A B 1000	_	4	18	μs
<u>-</u>	Response time	Fall time	t_{f}	V_{CE} =2V, I_{C} =2mA, R_{L} =100 Ω	_	3	18	μs

^{*5} From the production Date code "J5" (May 1997) to "P7" (July 2002), however the products were screened by BV_{CEO}≥70V.

^{*1} Pulse widths100µs, Duty ratio: 0.001 *2 40 to 60%RH, AC for 1minute, f=60Hz *3 For 10s

^{*4} Up to Date code "P7" (July 2002) V_{CEO}: 35V.



■ Model Line-up

Lead Form	Through-Hole	Wide Through-Hole	SMT G	ullwing	Wide SMT Gullwing		I _C [mA]	
Package	Sleeve			Taping		Rank mark	$(I_F=5mA, V_{CE}=5V, T_a=25^{\circ}C)$	
1 ackage	100pcs/sleeve			2 000pcs/reel				
	PC817X	PC817XF	PC817XI	PC817XP	PC817XFP	with or without	2.5 to 30.0	
	PC817X1	PC817XF1	PC817XI1	PC817XP1	_	A	4.0 to 8.0	
	PC817X2	PC817XF2	PC817XI2	PC817XP2	_	В	6.5 to 13.0	
	PC817X3	PC817XF3	PC817XI3	PC817XP3	_	С	10.0 to 20.0	
	PC817X4	PC817XF4	PC817XI4	PC817XP4	-	D	15.0 to 30.0	
Model No.	PC817X5	PC817XF5	PC817XI5	PC817XP5	-	A or B	4.0 to 13.0	
	PC817X6	PC817XF6	PC817XI6	PC817XP6	-	B or C	6.5 to 20.0	
	PC817X7	PC817XF7	PC817XI7	PC817XP7	-	C or D	10.0 to 30.0	
_	PC817X8	PC817XF8	PC817XI8	PC817XP8	-	A, B or C	4.0 to 20.0	
	PC817X9	PC817XF9	PC817XI9	PC817XP9	_	B, C or D	6.5 to 30.0	
	PC817X0	PC817XF0	PC817XI0	PC817XP0	-	A, B, C or D	4.0 to 30.0	

Please contact a local SHARP sales representative to inquire about production status and Lead-Free options.



Fig.1 Forward Current vs. Ambient Temperature

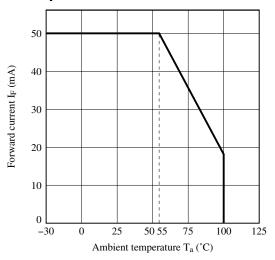


Fig.3 Collector Power Dissipation vs. Ambient Temperature

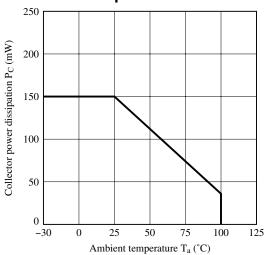


Fig.5 Peak Forward Current vs. Duty Ratio

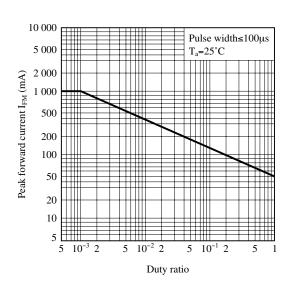


Fig.2 Diode Power Dissipation vs.
Ambient Temperature

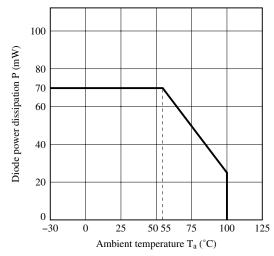


Fig.4 Total Power Dissipation vs. Ambient Temperature

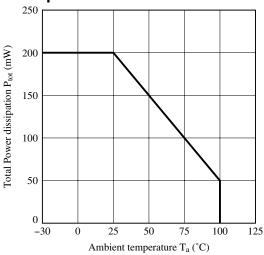


Fig.6 Current Transfer Ratio vs. Forward Current

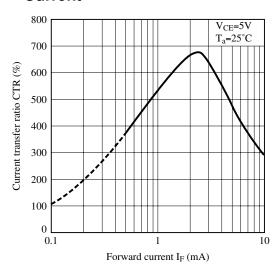




Fig.7 Forward Current vs. Forward Voltage

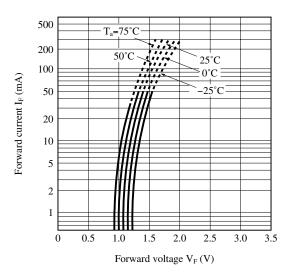


Fig.9 Relative Current Transfer Ratio vs. Ambient Temperature

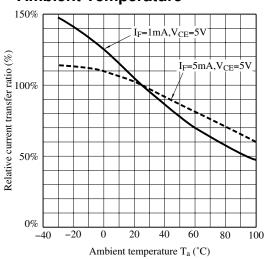


Fig.11 Collector Dark Current vs. Ambient Temperature

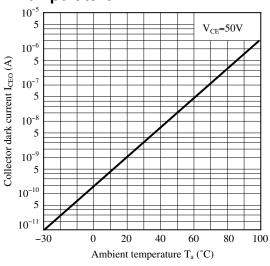


Fig.8 Collector Current vs. Collector-emitter Voltage

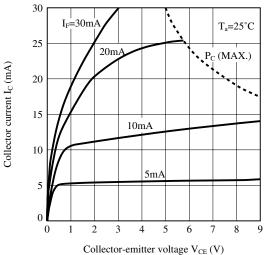


Fig.10 Collector - emitter Saturation Voltage vs. Ambient Temperature

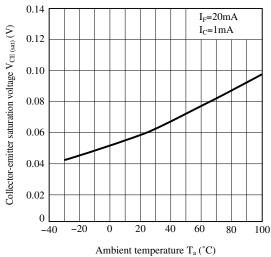


Fig.12 Collector-emitter Saturation Voltage vs. Forward Current

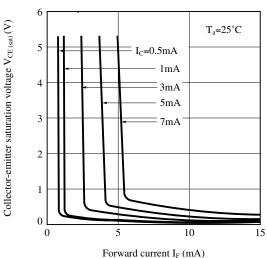
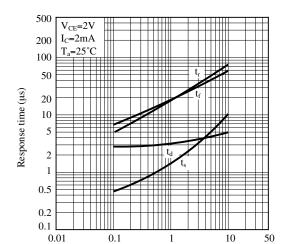


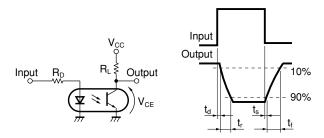


Fig.13 Response Time vs. Load Resistance



Load resistance $R_L(k\Omega)$

Fig.14 Test Circuit for Response Time



Please refer to the conditions in Fig.13.

Fig.15 Frequency Response

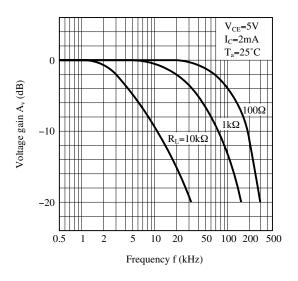
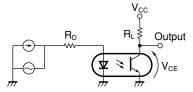


Fig.16 Test Circuit for Frequency Response



Please refer to the conditions in Fig.15.

Remarks: Please be aware that all data in the graph are just for reference and not for guarantee.



■ Design Considerations

Design guide

While operating at I_F<1.0mA, CTR variation may increase.

Please make design considering this fact.

This product is not designed against irradiation and incorporates non-coherent IRED.

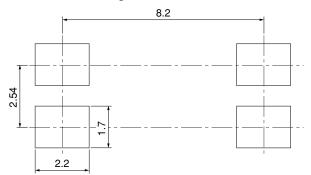
Degradation

In general, the emission of the IRED used in photocouplers will degrade over time.

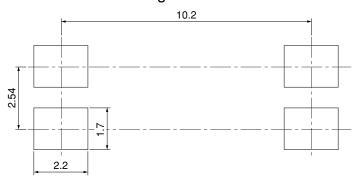
In the case of long term operation, please take the general IRED degradation (50% degradation over 5years) into the design consideration.

Recommended Foot Print (reference)

SMT Gullwing Lead-form



Wide SMT Gullwing Lead-form



(Unit: mm)

[☆] For additional design assistance, please review our corresponding Optoelectronic Application Notes.



■ Manufacturing Guidelines

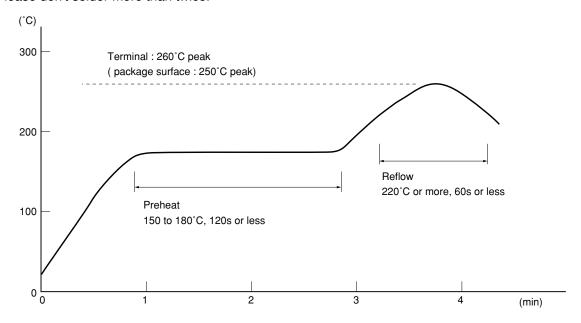
Soldering Method

Reflow Soldering:

Reflow soldering should follow the temperature profile shown below.

Soldering should not exceed the curve of temperature profile and time.

Please don't solder more than twice.



Flow Soldering:

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 270°C and within 10s.

Preheating is within the bounds of 100 to 150°C and 30 to 80s.

Please don't solder more than twice.

Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C.

Please don't solder more than twice.

Other notices

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.



Cleaning instructions

Solvent cleaning:

Solvent temperature should be 45°C or below Immersion time should be 3minutes or less

Ultrasonic cleaning:

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

Presence of ODC

This product shall not contain the following materials.

And they are not used in the production process for this device.

Regulation substances: CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

Sheet No.: D2-A03101EN



■ Package specification

Sleeve package

1. Through-Hole or SMT Gullwing Lead-Form

Package materials

Sleeve: HIPS (with anti-static material)

Stopper: Styrene-Elastomer

Package method

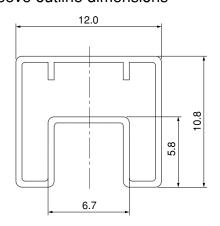
MAX. 100pcs of products shall be packaged in a sleeve.

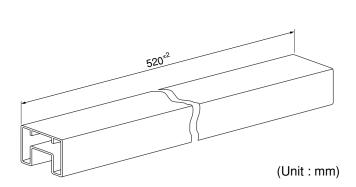
Both ends shall be closed by tabbed and tabless stoppers.

The product shall be arranged in the sleeve with its anode mark on the tabless stopper side.

MAX. 20 sleeves in one case.

Sleeve outline dimensions





2. Wide Through-Hole Lead-Form or Wide SMT Gullwing Lead-Form

Package materials

Sleeve: HIPS (with anti-static material)

Stopper: Styrene-Elastomer

Package method

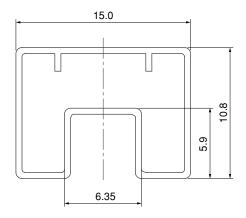
MAX. 100pcs of products shall be packaged in a sleeve.

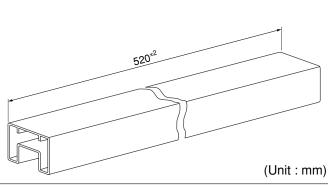
Both ends shall be closed by tabbed and tabless stoppers.

The product shall be arranged in the sleeve with its anode mark on the tabless stopper side.

MAX. 20 sleeves in one case.

Sleeve outline dimensions





Sheet No.: D2-A03101EN



● Tape and Reel package

1. SMT Gullwing

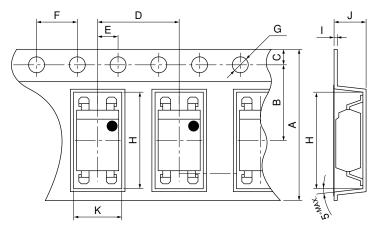
Package materials

Carrier tape: PS

Cover tape: PET (three layer system)

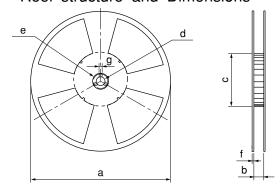
Reel: PS

Carrier tape structure and Dimensions



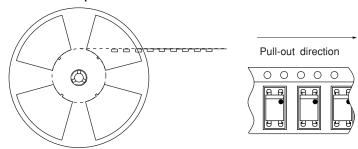
Dimensions List (Unit: mm)						
A	В	С	D	Е	F	G
16.0 ^{±0.3}	7.5 ^{±0.1}	1.75 ^{±0.1}	8.0 ^{±0.1}	2.0 ^{±0.1}	4.0 ^{±0.1}	φ1.5 + 8.1
Н	I	J	K			
10.4 ^{±0.1}	0.4±0.05	4.2 ^{±0.1}	5.1 ^{±0.1}			

Reel structure and Dimensions



Dimensio	ns List	(Unit: mm)			
a	b	c	d		
330	17.5 ^{±1.5}	100±1.0	13±0.5		
e	f	g			
23 ^{±1.0}	2.0 ^{±0.5}	2.0 ^{±0.5}			

Direction of product insertion



[Packing: 2 000pcs/reel]



2. Wide SMT Gullwing

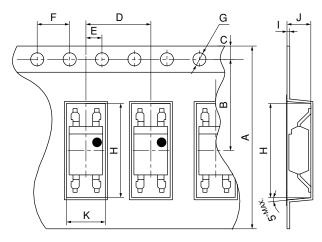
Package materials

Carrier tape : PS

Cover tape: PET (three layer system)

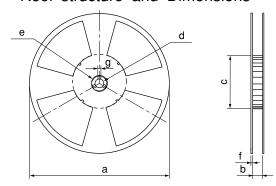
Reel: PS

Carrier tape structure and Dimensions



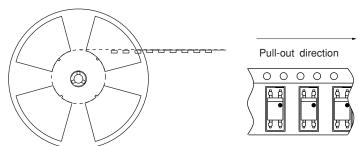
Dimensior	ns List	(Unit: mm				
A	В	С	D	Е	F	G
24.0 ^{±0.3}	11.5 ^{±0.1}	1.75 ^{±0.1}	8.0 ^{±0.1}	2.0 ^{±0.1}	4.0 ^{±0.1}	φ1.5 + 8.1
Н	I	J	K			
12 /±0.1	0.4±0.05	/ 1±0.1	5 1±0.1			

Reel structure and Dimensions



Dimensio	ns List	(Unit: mm)			
a	b	c	d		
330	25.5±1.5	100±1.0	13±0.5		
e	f	g			
23±1.0	2.0±0.5	2.0 ^{±0.5}			

Direction of product insertion



[Packing: 2 000pcs/reel]



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 - --- Office automation equipment
 - --- Telecommunication equipment [terminal]
 - --- Test and measurement equipment
 - --- Industrial control
 - --- Audio visual equipment
 - --- Consumer electronics
- (ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection

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- --- Gas leakage sensor breakers
- --- Alarm equipment
- --- Various safety devices, etc.
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